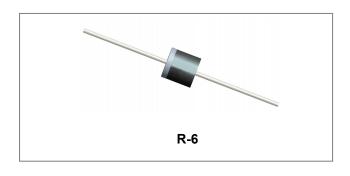






8SQ045 SCHOTTKY BARRIER RECTIFIER



Features

- Super-high speed & low noise switching
- Low voltage drop
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Mechanical Data

- DC-DC converters
- AC adapter
- · High frequency rectification circuit
- Bypass diodes

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	45	V
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @T _L = 119°C, rectangular wave form	8	Α
Peak One Cycle Non-Repetitive Surge Current	I _{FSM}	8.3 ms, half Sine pulse	200	Α

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V _{F1}	@ 8 A, Pulse, T _J = 25 °C	0.50	0.53	V
	V _{F2}	@ 8 A, Pulse, T _J = 125 °C	-	0.44	V
Reverse Current*	I _{R1}	@V _R = rated V _R , T _J = 25 °C	0.03	1.0	mA
	I _{R2}	@V _R = rated V _R , T _J = 125 °C	15	60.0	mA
Junction Capacitance	Ст	$@V_R = 5V, T_C = 25 °C$ $f_{SIG} = 1MHz$	500	900	pF

^{*} Pulse width < 300 µs, duty cycle < 2%



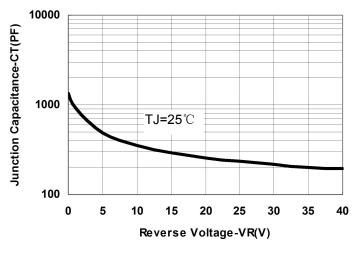




Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance, Case to Heat Sink	R _{θJA}	-	18	°C/W
Typical Thermal Resistance, Junction to lead	$R_{ heta JL}$	-	8	°C/W
Approximate Weight	wt	-	2.24	g
Case Style		R-6		

Ratings and Characteristics Curves



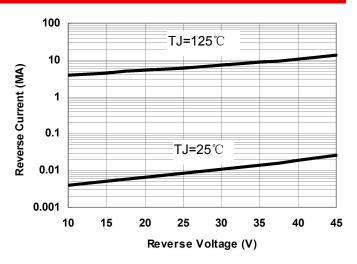
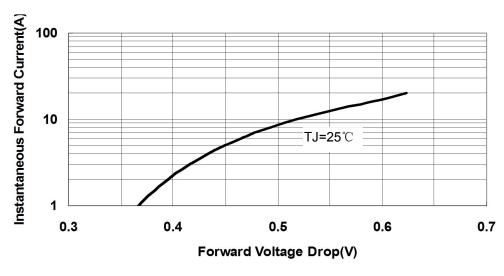


Fig.1-Typical Junction Capacitance

Fig.2-Typical Values Of Reverse Current



• China - Germany - Korea - Singapore - United States •

Fig.3-Typical Instantaneous Forward Voltage Characteristics

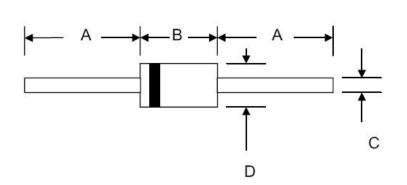
• http://www.smc-diodes.com - sales@ smc-diodes.com •







Mechanical Dimensions R-6



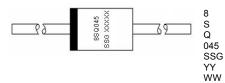
CVMPOL	Millimeters		Inches		
SYMBOL	Min.	Max.	Min.	Max.	
Α	25.4	-	1.000	-	
В	8.60	9.10	0.340	0.360	
С	1.2	1.3	0.048	0.052	
D	8.60	9.10	0.340	0.360	

Ordering Information

Device	Package	Shipping	
8SQ045	R-6(Pb-Free)	500pcs / reel	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

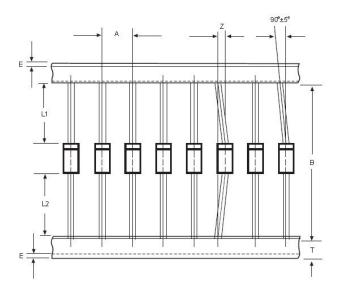
Marking Diagram



Where XXXXX is YYWWL

- = Forward Current (8A)
- = Package Type = Device Type = Reverse Voltage (45V)
- G = SSG = Year
 - = Year = Week
- = Week
 - = Lot Number

Carrier Tape Specification R-6



SYMBOL	Millimeters		
STWIBOL	Min.	Max.	
А	9.50	10.50	
В	50.9	53.9	
Z	-	1.20	
Т	5.60	6.40	
E	-	0.80	
IL1-L2I	-	1.0	

- China Germany Korea Singapore United States •
- http://www.smc-diodes.com sales@ smc-diodes.com •







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